

TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

MT4S07

VHF~UHF Band Low Noise Amplifier Applications

Unit: mm

•	Low Noise Figure: NF = 1.5dB
	$(V_{CE} = 3 \text{ V}, I_{C} = 5 \text{ mA}, f = 2 \text{ GHz})$
_	High Gain: \$210 2 - 9 5dB

• High Gain: $|S21e|^2 = 9.5 \text{dB}$ (VCE = 3 V, IC = 15 mA, f = 2 GHz)

Maximum Ratings (Ta = 25°C)

項目	記号	定格	単位	
Collector-base voltage	V_{CBO}	10	V	
Collector-emitter voltage	V _{CEO}	5	V	
Emitter-base voltage	V _{EBO}	1.5	V	
Collector current	IC	25	mA	
Base current	ΙΒ	10	mA	
Collector power dissipation	PC	150	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	Tstg	-55~125	°C	

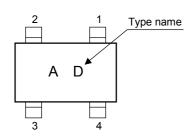
1, 3. EMITTER 2. BASE SMQ 4. COLLECTOR JEDEC — JEITA

2-3J1C

Weight: 0.012 g (typ.)

TOSHIBA

Marking



Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Transition frequency	f _T	$V_{CE} = 3 \text{ V}, I_{C} = 10 \text{ mA}$	10	12	_	GHz
Insertion gain	S21e ² (1)	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}, f = 2 \text{ GHz}$		8		dB
insertion gain	S21e ² (2)	$V_{CE} = 3 \text{ V}, I_{C} = 15 \text{ mA}, f = 2 \text{ GHz}$	7.5	10.5	_	иБ
Noise figure	NF(1)	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}, f = 2 \text{ GHz}$	_	1.6	3	dB
INDISE ligure	NF(2)	$V_{CE} = 3 \text{ V}, I_{C} = 5 \text{ mA}, f = 2 \text{ GHz}$	_	1.5	3	ub

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 5 \text{ V}, I_{E} = 0$	_	_	0.1	μΑ
Emitter cut-off current	I _{EBO}	$V_{EB} = 1 \text{ V, } I_{C} = 0$			1	μА
DC current gain	h _{FE}	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}$	70	_	140	_
Reverse transfer capacitance	C _{re}	$V_{CB} = 1 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$ (Note)		0.4	0.85	pF

Note: C_{re} is measured by 3 terminal method with capacitance bridge.

Caution

This device electrostatic sensitivity. Please handle with caution

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